TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74HC151AP, TC74HC151AF, TC74HC151AFN

8 – CHANNEL MULTIPLEXER

The TC74HC151A is a high speed CMOS 8 - CHANNEL MULTIPLEXER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

One of eight date input signals (D0 - D7) is selected by decoding of the three - bit address input (A, B, C). The selected data appears on two outputs : non - inverting (Y) and inverting (W).

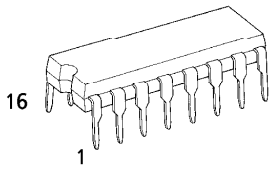
The strobe input provides two output conditions ; a low level on the strobe input transferrs the selected data to the outputs. A high level on the strobe input sets the Y output low and the W output high without regard to the data or select input conditions.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

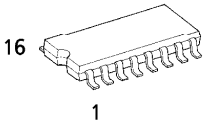
FEATURES :

- High Speed ····· t_{pd} = 15ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ····· I_{CC} = 4μA(Max.) at Ta = 25°C
- High Noise Immunity ····· $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min.)
- Output Drive Capability ····· 10 LSTTL Loads
- Symmetrical Output Impedance ··· $|I_{OH}| = I_{OL}$ = 4mA(Min.)
- Balanced Propagation Delays ····· $t_{pLH} \simeq t_{pHL}$
- Wide Operating Voltage Range ···· V_{CC} (opr.) = 2V ~ 6V
- Pin and Function Compatible with 74LS151

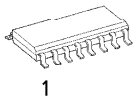
(Note) The JEDEC SOP (FN) is not available in Japan.



P (DIP16-P-300-2.54A)
Weight : 1.00g (Typ.)

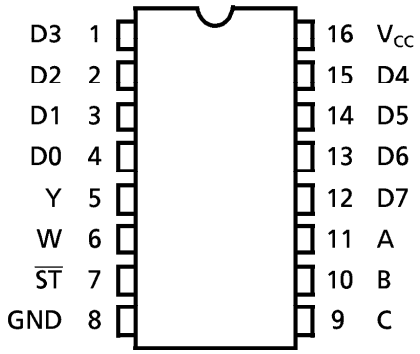


F (SOP16-P-300-1.27)
Weight : 0.18g (Typ.)



FN (SOL16-P-150-1.27)
Weight : 0.13g (Typ.)

PIN ASSIGNMENT



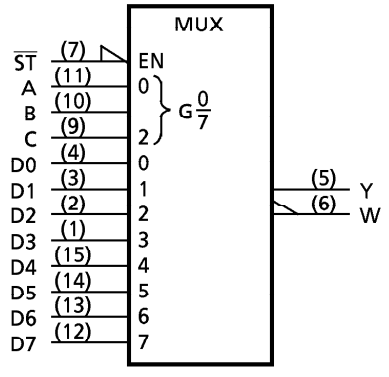
(TOP VIEW)

TRUTH TABLE

INPUTS				OUTPUTS	
SELECT			STROBE	Y	W
C	B	A	$\overline{ST}$		
X	X	X	H	L	H
L	L	L	L	D0	$\overline{D0}$
L	L	H	L	D1	$\overline{D1}$
L	H	L	L	D2	$\overline{D2}$
L	H	H	L	D3	$\overline{D3}$
H	L	L	L	D4	$\overline{D4}$
H	L	H	L	D5	$\overline{D5}$
H	H	L	L	D6	$\overline{D6}$
H	H	H	L	D7	$\overline{D7}$

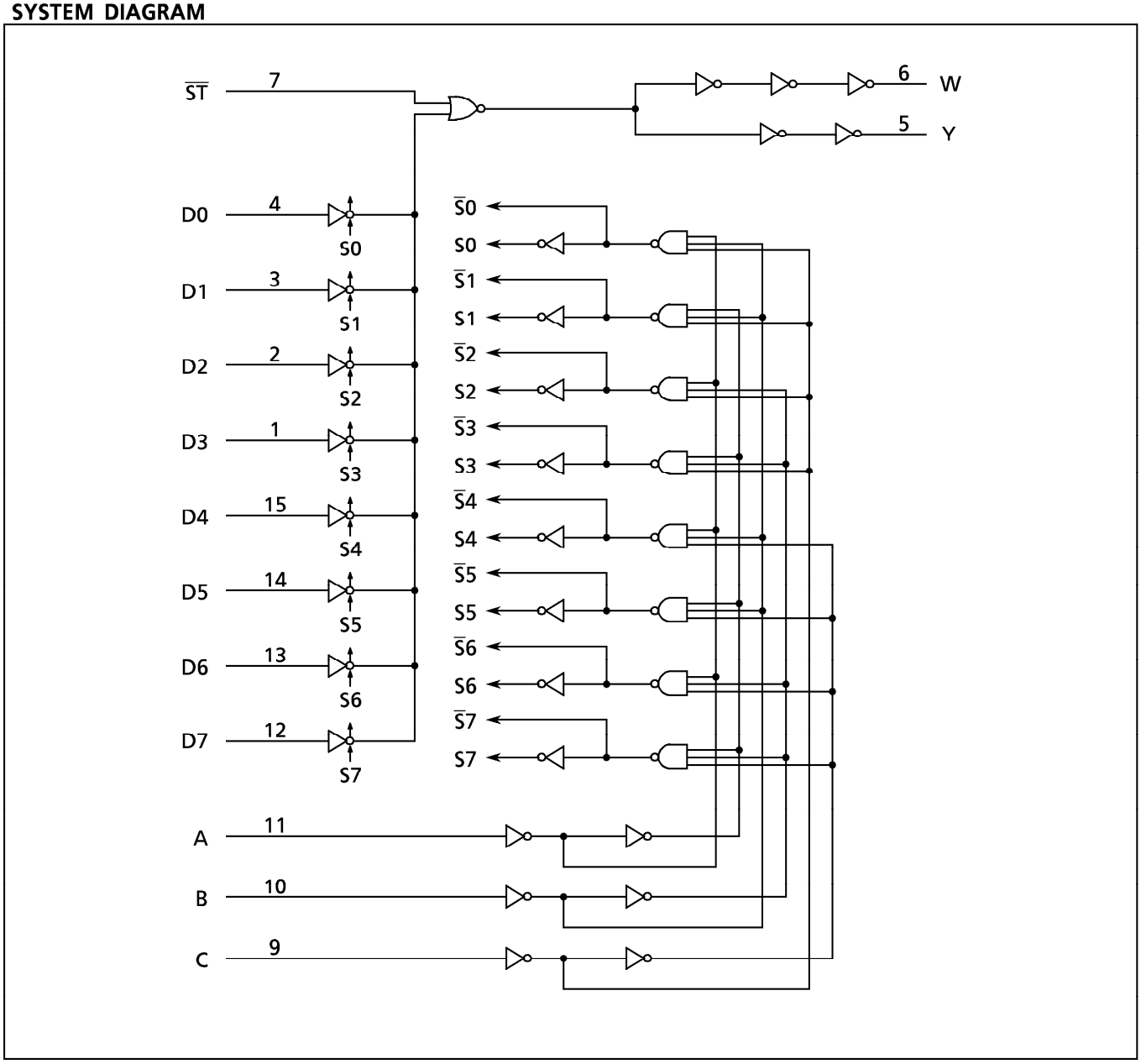
X : Don't Care

IEC LOGIC SYMBOL



961001EBA2

SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	−0.5~7	V
DC Input Voltage	V_{IN}	−0.5~V_{CC}+0.5	V
DC Output Voltage	V_{OUT}	−0.5~V_{CC}+0.5	V
Input Diode Current	I_{IK}	±20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current	I_{OUT}	±25	mA
DC V_{CC} / Ground Current	I_{CC}	±50	mA
Power Dissipation	P_D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T_{stg}	−65~150	°C

*500mW in the range of Ta= −40°C~65°C. From Ta=65°C to 85 °C a derating factor of −10mW/ °C shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2~6	V
Input Voltage	V_{IN}	0~V_{CC}	V
Output Voltage	V_{OUT}	0~V_{CC}	V
Operating Temperature	T_{opr}	−40~85	°C
Input Rise and Fall Time	t_r, t_f	0~ 1000 (V_{CC} = 2.0V) 0~ 500 (V_{CC} = 4.5V) 0~ 400 (V_{CC} = 6.0V)	ns

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V_{CC} (V)	Ta = 25°C MIN.	Ta = 25°C TYP.	Ta = 25°C MAX.	Ta = −40~85°C MIN.	Ta = −40~85°C MAX.	UNIT
High - Level Input Voltage	V_{IH}			2.0 4.5 6.0	1.50 3.15 4.20	− − −	− − −	1.50 3.15 4.20	− − −	V
Low - Level Input Voltage	V_{IL}			2.0 4.5 6.0	− − −	− − −	0.50 1.35 1.80	− − −	0.50 1.35 1.80	V
High - Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −20μA	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	− − −	1.9 4.4 5.9	− − −	V
			I_{OH} = −4 mA I_{OH} = −5.2mA	4.5 6.0	4.18 5.68	4.31 5.80	− −	4.13 5.63	− −	
Low - Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 20μA	2.0 4.5 6.0	− − −	0.0 0.0 0.0	0.1 0.1 0.1	− − −	0.1 0.1 0.1	V
			I_{OL} = 4 mA I_{OL} = 5.2mA	4.5 6.0	− −	0.17 0.18	0.26 0.26	− −	0.33 0.33	
Input Leakage Current	I_{IN}	V_{IN} = V_{CC} or GND		6.0	−	−	±0.1	−	±1.0	μA
Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND		6.0	−	−	4.0	−	40.0	

AC ELECTRICAL CHARACTERISTICS (C_L = 15pF, V_{CC} = 5V, Ta = 25°C, Input $t_r = t_f$ = 6ns)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t_{TLH} t_{THL}		—	4	8	ns
Propagation Delay Time (D−Y)	t_{pLH} t_{pHL}		—	15	24	
Propagation Delay Time (D−W)	t_{pLH} t_{pHL}		—	15	24	
Propagation Delay Time ($\overline{ST}$−Y)	t_{pLH} t_{pHL}		—	10	17	
Propagation Delay Time ($\overline{ST}$−W)	t_{pLH} t_{pHL}		—	10	17	
Propagation Delay Time (A, B, C−Y)	t_{pLH} t_{pHL}		—	19	31	
Propagation Delay Time (A, B, C−W)	t_{pLH} t_{pHL}		—	19	31	

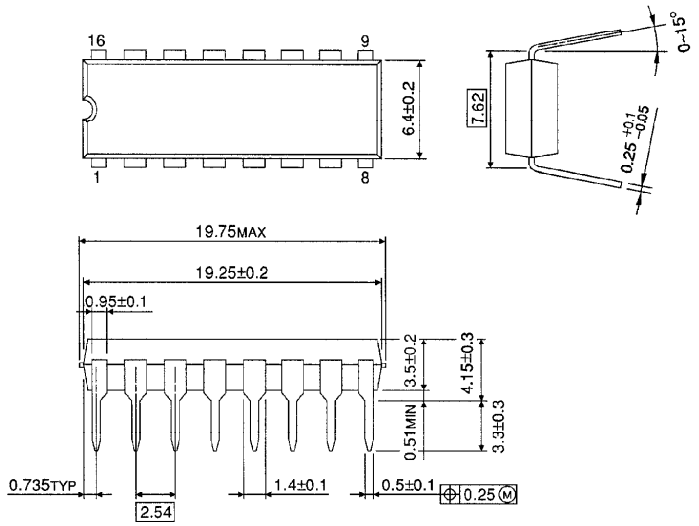
AC ELECTRICAL CHARACTERISTICS (C_L = 50pF, Input $t_r = t_f$ = 6ns)

PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C			Ta = −40~85°C		UNIT
			V_{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	t_{TLH} t_{THL}		2.0 4.5 6.0	— — —	30 8 7	75 15 13	— — —	95 19 16	ns
Propagation Delay Time (D−Y)	t_{pLH} t_{pHL}		2.0 4.5 6.0	— — —	65 18 15	140 28 24	— — —	175 35 30	
Propagation Delay Time (D−W)	t_{pLH} t_{pHL}		2.0 4.5 6.0	— — —	65 18 15	140 28 24	— — —	175 35 30	
Propagation Delay Time ($\overline{ST}$−Y)	t_{pLH} t_{pHL}		2.0 4.5 6.0	— — —	36 12 10	100 20 17	— — —	125 25 21	
Propagation Delay Time ($\overline{ST}$−W)	t_{pLH} t_{pHL}		2.0 4.5 6.0	— — —	36 12 10	100 20 17	— — —	125 25 21	
Propagation Delay Time (A, B, C−Y)	t_{pLH} t_{pHL}		2.0 4.5 6.0	— — —	80 23 19	180 36 31	— — —	225 45 38	
Propagation Delay Time (A, B, C−W)	t_{pLH} t_{pHL}		2.0 4.5 6.0	— — —	80 23 19	180 36 31	— — —	225 45 38	
Input Capacitance	C_{IN}			—	5	10	—	10	pF
Power Dissipation Capacitance	C_{PD} (1)			—	69	—	—	—	

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:

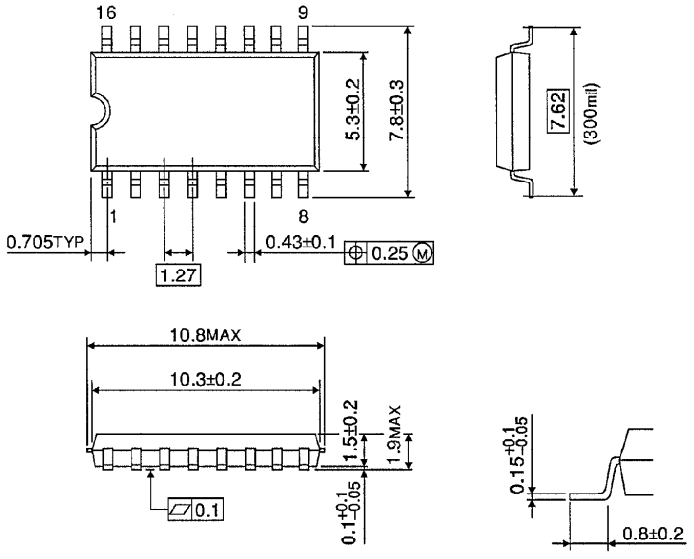
$$I_{CC}(opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

DIP 16PIN OUTLINE DRAWING (DIP16-P-300-2.54A) Unit in mm



Weight : 1.00g (Typ.)

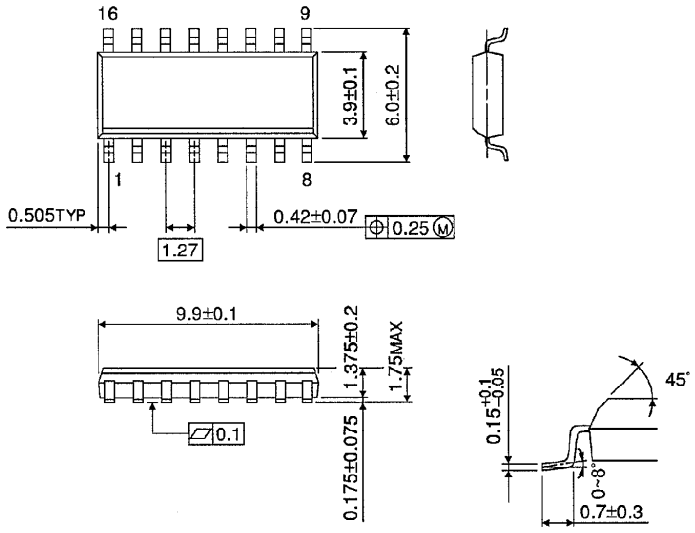
SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300-1.27) Unit in mm



Weight : 0.18g (Typ.)

SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL14-P-150 -1.27) Unit in mm

(Note) This package is not available in Japan.



Weight : 0.13g (Typ.)